GP2W3270XP0F

IrDA Compliant Transceiver Module 9.6 to 115.2 kb/s (SIR LP) Low Profile Low Consumption Current



Description

The **GP2W3270XP0F** is an infrared transceiver module for IrDA ver. 1.4 (SIR LP). The transceiver consisits of a pin-photo diode, infrared emitter and control IC in a single package. This device is built in LED constant current circuit. This device have remote control transmission function (built in drive circuit).

Features

- 1. Compliant with the IrDA 1.4 (SIR LP) Transmission speed : 9.6 to 115.2 kb/s Transmission distance : 20 cm
- 2. Small package $L 8.3 \times W 2.1 \times H 1.7 \text{ mm}$
- 3. Peak emission wavelength : 890 nm (Buit-in shared single LED for RC and IrDA)
- 4. Top view type
- 5. Soldering reflow type
- 6. Shield type
- Low consumption current due to shutdown function (Consumption current at shutdown mode : Max. 0.1 μA)
- 8. Operates from 2.4 to 3.6 V
- 9. With built in LED constant circuit
- 10. With remote control function (buit in drive circuit)
- 11. With VIO terminal

■Agency approvals/Compliance

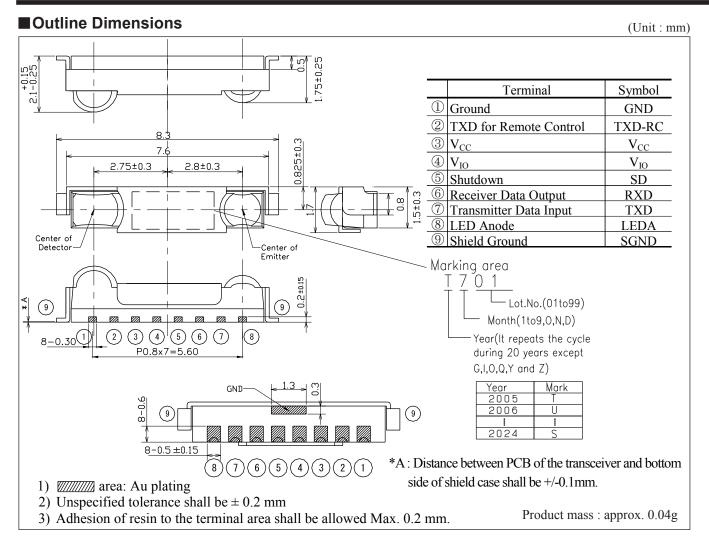
- 1. Compliant with IEC60825-1 class 1 eye safety standard
- 2. Compliant with RoHS directive (2002/95/EC)
- Content status of six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (popular name : *China RoHS*) (Chinese : 电子信息产品污染控制管理办法) ; refer to page 13
- 4. Lead (Pb) free device

Applications

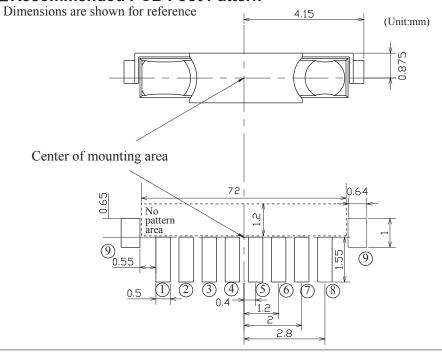
- 1. Mobile equipment
- (Cellular phone, Pager, Smart phone, PDAs, Portable printer, etc.)
- 2. Digital imaging equipment (Digital camera, Photo imaging printer)
- 3. POS equipment

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GP2W3270XP0F



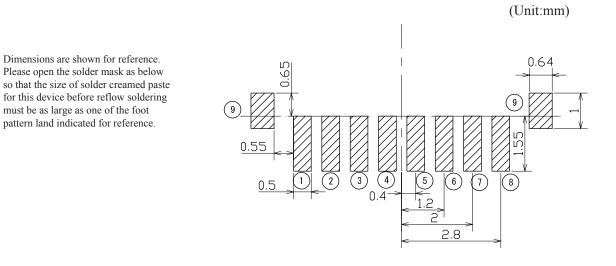
Recommended PCB Foot Pattern



Sheet No.: E3-A01201EN



Recommended Size of Solder Creamed Paste (Reference)



Solder paste area

Sheet No.: E3-A01201EN



Absolute Maximum Ratings (Ta=25°C)							
Parameter	Symbol	Rating	Unit				
Supply voltage	V _{CC}	0 to 6.0	V				
VI/O Supply voltage	V _{IO}	0 to V_{CC}	V				
LED Supply voltage	V _{LEDA}	0 to 7.0	V				
SD,TXD Input voltage	V_{SD}, V_{TXD}	0 to V_{IO} +0.3	V				
TXD-RC Input voltage	V _{TXDRC}	0 to V_{IO} +0.3	V				
Peak forward current 1	I _{FM1}	120	mA				
Peak forward current 2	I _{FM2}	300	mA				
Operating temperature	T _{opr}	-40 to +85	°C				
Storage temperature	T _{stg}	-40 to +85	°C				
Soldering temperature	T _{sol}	260	°C				
	Parameter Supply voltage VI/O Supply voltage LED Supply voltage SD,TXD Input voltage TXD-RC Input voltage Peak forward current 1 Peak forward current 2 Operating temperature Storage temperature	ParameterSymbolSupply voltage V_{CC} VI/O Supply voltage V_{IO} LED Supply voltage V_{LEDA} SD,TXD Input voltage V_{SD},V_{TXD} TXD-RC Input voltage V_{TXDRC} Peak forward current 1 I_{FM1} Peak forward current 2 I_{FM2} Operating temperature T_{opr} Storage temperature T_{stg}	ParameterSymbolRatingSupply voltage V_{CC} 0 to 6.0VI/O Supply voltage V_{IO} 0 to V_{CC} LED Supply voltage V_{LEDA} 0 to 7.0SD,TXD Input voltage V_{SD} , V_{TXD} 0 to V_{IO} +0.3TXD-RC Input voltage V_{TXDRC} 0 to V_{IO} +0.3Peak forward current 1 I_{FM1} 120Peak forward current 2 I_{FM2} 300Operating temperature T_{opr} -40 to +85Storage temperature T_{stg} -40 to +85				

*1 Pulse width: 78.1μs, Duty ratio: 3/16
*2 Pulse width: 17.9μs, Duty ratio: 1/4
*3 Soldering reflow time: 10s

■Electrical Characteristics

 $(T_a=25^{\circ}C, V_{CC}=3.3V)$

Parameter		Symbol	Rating		TYP.	MAX.	Unit
Current consumption at no input signal		I _{CC}	No input signal, output terminal open, V _{IHSD} =0V		70	100	μΑ
	rrent consumption Shutdown mode	I _{CC-S}	No input signal, output terminal open, $V_{IHSD}=V_{CC}$		0.001	0.1	μΑ
Hig	gh level output voltage	V _{OH}	V_{CC} =2.4 to 3.6V, I_{OH} =200 μA^{*4}	V_{IO} -0.4	_	_	V
Lo	w level output voltage	V _{OL}	$V_{CC}=2.4$ to 3.6V, $I_{OL}=200\mu A^{*4}$			0.4	V
Ris	e time	t _r				0.06	μs
Fal	l time	t _f	9.6 kb/s \leq BR \leq 115.2kb/s, C _L =10pF, $\phi \leq$ 15° ^{*4}			0.06	μs
Lo	w level pulse width	t _w		1.35	2.25	3.3	μs
Ma	ximum reception distance	L	9.6 kb/s \leq BR \leq 115.2kb/s, C _L =10pF, $\phi \leq$ 15° ^{*4}	21		—	cm
Input irradiance		Ee	9.6 kb/s \leq BR \leq 115.2kb/s, C _L =10pF, $\phi \leq$ 15° ^{*4}		_	0.081	W/m ²
Receiver wakeup Latency		tı		—		200	μs
Re	ceiver wakeup time	t _{sdw}	No input signal	—		200	μs
	Radiant intensity	IE			_	28	mW/sr
	LED peak current	I _{LED}	BR=115.2kb/s, $\phi \leq 15^\circ$,	43	60	80	mA
IrDA	Rise time	t _r	$V_{\rm IHTXD} = 2.8 V^{*5}$		—	0.6	μs
Ξ	Fall time	t _f			—	0.6	μs
	Peak emission wavelength	λ_{p}		875	890	900	nm
	Maximum optical pulse width	T _{OPWM}	TXD pin stuck High		80	250	μs
	Transmit distance	L _{RC}		4			m
	Radiant intensity	I _{ERC}	f=40kHz,duty=25%, $\phi = 0^{\circ}$,	20	—	100	mW/sr
RC	LED peak current	ILEDRC	$V_{IHTXD}=2.8V^{*5}$		200	260	mA
	Peak emission wavelength	$\lambda_{\rm p}$			890		nm
	Maximum optical pulse width	T _{OPWM}	TXD pin stuck High	30	80	250	μs

*4 Refer to Fig.2, 3, 4 *5 Refer to Fig.5, 6, 7

Recommended Operating Conditions

Parameter	Symbol	Conditions	Rating	Unit
Supply voltage	V _{CC}		2.4 to 3.6	V
V _{IO} voltage	V _{IO}		1.5 to V_{CC}	V
LED Supply voltage	V _{LEDA}		V_{CC} -0.5 to 6.5	V
Operating temperature	T _{opr}		-25 to +85	°C
Data rate	BR		9.6 to 115.2	kb/s
SD terminal input voltage Logic High	V _{IHSD}	Shutdown mode, $2.4V \leq V_{IO}$	$V_{CC} \times 0.67$ to V_{CC}	V
SD terminal input voltage Logic Low	V _{ILSD}	Normal mode,2.4V \leq V _{IO}	0.0 to $V_{CC} \times 0.33$	V
TDX high level input voltage	V _{IHTXD}	LED ON *6	$V_{IO}\!\!\times\!\!0.67$ to V_{IO}	V
TDX low level input voltage	V _{ILXTD}	LED OFF ^{*6}	0.0 to $V_{IO} \times 0.33$	V
TDX-RC high level input voltage	V _{IHTXDRC}	LED ON ^{*6}	$V_{IO}\!\!\times\!\!0.67$ to V_{IO}	V
TDX-RC low level input voltage	V _{ILXTDRC}	LED OFF ^{*6}	0.0 to $V_{IO} \times 0.33$	V

*6 Refer to Fig.7

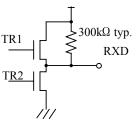


GP2W3270XP0F

Truth Table

Mode	SD	TXD	TXD-RC	Input signal	LED	RXD
Normal mode	0	0	0	No	Off	1
	0	0	0	IrDA	Off	0**
	0	0	1	*	On(60mA)	0
IrDA operation	0	1	0	*	On(60mA)	0
Remote control operation	1	0	1	*	On(200mA)	pull-up
Shutdown mode	1	0	0	*	Off	pull-up

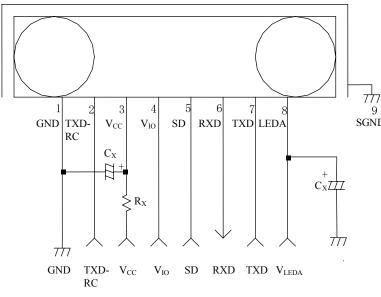
* RXD Equipment circuit



* Don't care

** The pulse width is constant without depending on the transmission rate and the light intensity of input signal.

Fig.1 Recommended External Circuit



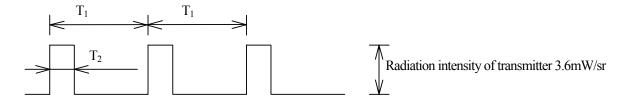
Components circuit	Recommended values
C _X	1µF/6.3V(Note)
R _X	1 to 15 Ω

(Note) Please choose the most suitable Cx according to the noise level and noise frequency of power supply.

SGND Depending on noise level and noise frequency of power supply, Cx does not work well. There are cases that some pulse noises from RXD other than signal will occur in certain communication area. Please check by finish product that there are no problem at all communication area and data rate. If there are any problem, please check by inserting R_x (1 to 15 Ω)in the circuit drawing. Although there is no problem to distribute the voltage supply of Vcc, VIO, and VLED terminal, please apply the voltage to Vcc terminal first.



Fig.2 Input Signal Waveform(Receiver side)



 $9.6kb/s \le BR(=1/T_1) \le 115.2kb/s$ $1.41\mu s \le T_2 \le 22\mu s$

Fig.3 Output Waveform Specification(Receiver side)

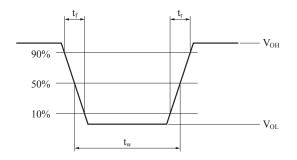
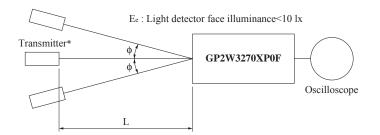


Fig.4 Standard Optical System(Receiver side)



 $\boldsymbol{\varphi}$: Indicates horizontal and vertical directions.

^{*}Transmitter shall use GP2W3270XP0F (λp =890nm TYP.) which is adjusted the radiation intensity at 3.6mW/sr.



Fig.5 Output Waveform Specification(Transmitter side)

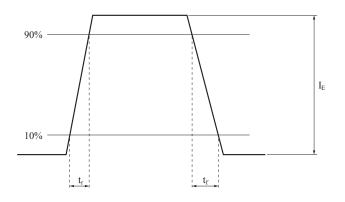


Fig.6 Standard Optical System(Transmitter side)

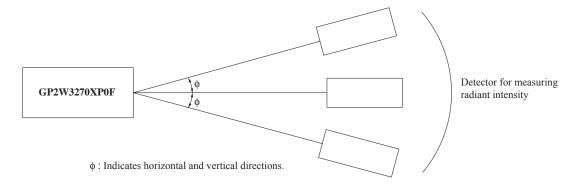
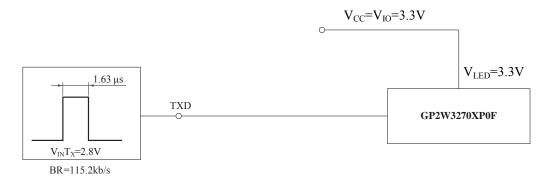


Fig.7 Recommended Circuit of Transmitter side





■Notes

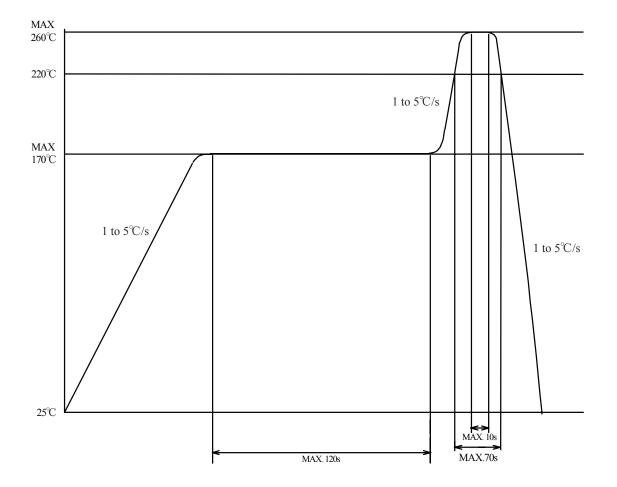
- When the system (program) is designed, the Turn Around Time shall be secured by considering 500 µs or more that is specified to IrDA. Then, this Turn Around Time means the time when this device does not temporarily detect the signal light, since the transmitted light form the transceiver reaches the detector side of the transceiver.
- (2) As it is necessary 200 μs or more (at Ta =25 °C, no input signal) to return from shut-down mode to readyoperation mode, please consider this point at the system (program) designing. Also, please confirm thoroughly the operation in actual application.
- (3) When there is much external disturbing light source is located near this transceiver and the detector face resceiver much external disturbing light, there is case that the pulse other than signal output is generated as noise on output terminal of this transceiver. Please consider the lay-out and structure to reduce disturbing light on the detector face.
- (4) In case that this sensor is adopted in IR communication system, please use it according to the signal method which is specified by [Serial Infrared Physical Layer Link Specification Version 1.4] published by Infrared Data Association. False operation may happen if the different signal method is used.
- (5) In circuit designing, make allowance for the degradation of light emitting diode output that results from long continuous operation. (50 % degradation/5 years)



Soldering Method

1. In case of solder reflow

Please carry out only two times soldering at the temperature and the time within the temperature profile as shown in the figure below. Reflow interval shall be within 3 days under conditions, 10 to 30°C, 70%RH or less.



2. Other precautions

An infrared lamp used to heat up for soldering may cause a localized temperature rise in the resin. So keep the package temperature within that specified in Item 1. Also avoid immersing the resin part in the solder. Even if within the temperature profile above, there is the possibility that the gold wire in package is broken in case that the deformation of PCB gives the affection to lead pins. Please use after confirming the conditions fully by actual solder reflow machine.

3. Soldering

- Soldering iron shall be less than 25W, and temperature of point of soldering iron shall use at 350° C or less.
- Soldering time shall be within 5s.
- Soldered product shall treat at normal temperature.



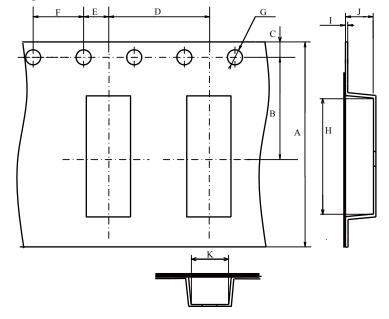
■Package specification

• Tape and Reel package 2000pcs/reel

Taping	materials
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Name	Material	Countermeasure for ESD
Reel	PPE	Coped(conductivity)
Carrier tape	PC	Coped(conductivity)
Cover tape	PET	Coped(conductivity)

Carrier tape structure and Dimensions

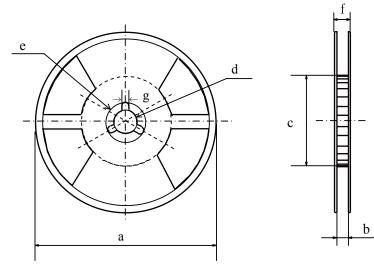


	(Unit : mm)					
	А	В	С	D	Е	F
	16.0±0.3	7.5±0.1	1.75±0.10	8.0±0.1	2.0±0.1	4.0±0.1
	G	Н	Ι	J	K	
	$\phi 1.5^{+0.1}_{-0.0}$	8.5±0.1	0.33±0.05	2.5±0.1	1.8±0.1	



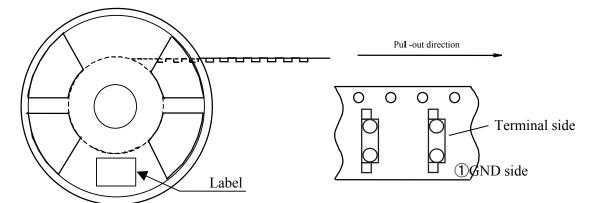
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Reel structure and Dimensions



Dimension List			(Unit : mm)
а	b	с	d
330±2	17.5±1.0	100±1	13±0.2
e	f	g	
21±0.8	22.4±1.0	2±0.5	

Direction of product insertion





Cleaning Instructions

Solvent cleaning :

Solvent temperature 45°C or less, Immersion for 3 min or less

Ultrasonic cleaning :

The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power output, cleaning time, PCB size or device mounting condition etc.

Please test it in actual using condition and confirm that doesn't occur any defect before starting the ultrasonic cleaning. The cleaning shall be carried out with solvent below.

Recommended Solvent materials :

Ethyl alcohol, Methyl alcohol, Isopropyl alcohol

Presence of ODC etc.

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

• The RoHS directive (2002/95/EC)

This product complies with the RoHS directive (2002/95/EC).

Object substances: lead, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE)

• Content of six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (Chinese: 电子信息产品污染控制管理办法)

		Toxic and hazardous substances					
Category	Lead (Pb)	Mercury (Hg)	Cadmium (Cd)	Hexavalent chromium (Cr ⁶⁺)	Polybrominated biphenyls (PBB)	Polybrominated diphenyl ethers (PBDE)	
Infrared data communication device	~	~	~	~	\$	✓	

✓ : indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006 standard.



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